

# L1450-35K42

## NIR Stem Type LED with High Output Power

L1450-35K42 is an InGaAsP LED mounted on a TO-46 stem with an unspherical glass lens. It is designed for high output power use.

On forward bias, it emits a spectral band of radiation which peaks at 1450nm.

#### <Features>

- High Radiated Intensity

- High Reliability

### <Specifications>

Product Name: NIR LED Lamp
Type Number: L1450-35K42

3. Chip:

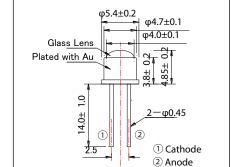
Chip material: InGaAs/InPPeak Wavelength: 1450nm

#### 4.Package

- Type: TO-46 Stem

- Lens: Unspherical Glass Lens

- Cap: Gold Plated



Outer Dimension (Unit:mm)

Absolute Maximum Ratings[Ta=25°C]							
Item	Symbol	Maximum Rated Value	Unit				
Power Dissipation	PD	130	mW				
Forward Current	IF	100	mA				
Pulse Forward Current*	IFP	500	mA				
Reverse Voltage	VR	5	V				
Junction Temperature	Tj	100	°C				
Thermal Resistance**	Rthja	330	K/W				
Operating Temperature	TOPR	-30 ~ +80	°C				
Storage Temperature	TSTG	-40 ~ +100	°C				
Soldering Temperature***	TSOL	265	°C				

<sup>\*</sup> Duty=1% and Pulse Width=10µs.

<sup>\*\*\*</sup> Soldering condition must be completed within 3 second at 265°C.

Electro-Optical Characteristics								
Item	Symbol	Condition	Minimum	Typical	Maximum	Unit		
Forward Voltage	VF	IF=50mA		1.0	1.3	V		
Total Radiated Power*	PO	IF=50mA	1.0	2.0		mW		
Radiant Intensity**	ΙE	IF=50mA		2.5		mW/sr		
Peak Wavelength	λP	IF=50mA	1400	1450	1500	nm		
Half Width	Δλ	IF=50mA		100		nm		
Viewing Half Angle	θ1/2	IF=50mA		±8		deg		
Rise Time	tr	IF=50mA		10		ns		
Fall Time	tr	IF=50mA		10		ns		

<sup>\*</sup> Measured by G8370-85



<sup>\*\*</sup> Junction - ambient, leads 7mm, soldered on PCB

<sup>\*\*</sup> Measured by Ando Optical Multi Meter AQ2140&AQ2742